

To our customers,

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## Old Company Name in Catalogs and Other Documents

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April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

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Not recommended  
for new design

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# MOS FIELD EFFECT TRANSISTOR NP82N06MLG, NP82N06NLG

## SWITCHING N-CHANNEL POWER MOS FET

### DESCRIPTION

The NP82N06MLG and NP82N06NLG are N-channel MOS Field Effect Transistors designed for high current switching applications.

### ORDERING INFORMATION

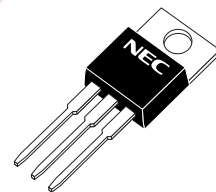
PART NUMBER	LEAD PLATING	PACKING	PACKAGE
NP82N06MLG-S18-AY <sup>Note</sup>	Pure Sn (Tin)	Tube	TO-220 (MP-25K) typ. 1.9 g
NP82N06NLG-S18-AY <sup>Note</sup>		50 p/tube	TO-262 (MP-25SK) typ. 1.8 g

**Note** Pb-free (This product does not contain Pb in the external electrode.)

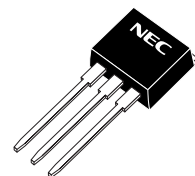
### FEATURES

- Logic level
- Built-in gate protection diode
- Super low on-state resistance
  - $R_{DS(on)1} = 7.4 \text{ m}\Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 41 \text{ A)}$
  - $R_{DS(on)2} = 9.7 \text{ m}\Omega \text{ MAX. (} V_{GS} = 5 \text{ V, } I_D = 41 \text{ A)}$
- High current rating
  - $I_{D(DC)} = \pm 82 \text{ A}$
- Low input capacitance
  - $C_{iss} = 5700 \text{ pF TYP.}$
- Designed for automotive application and AEC-Q101 qualified

(TO-220)



(TO-262)



### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C)

Drain to Source Voltage (V <sub>GS</sub> = 0 V)	V <sub>DSS</sub>	60	V
Gate to Source Voltage (V <sub>DS</sub> = 0 V)	V <sub>GSS</sub>	±20	V
Drain Current (DC) (T <sub>C</sub> = 25°C)	I <sub>D(DC)</sub>	±82	A
Drain Current (pulse) <sup>Note1</sup>	I <sub>D(pulse)</sub>	±270	A
Total Power Dissipation (T <sub>C</sub> = 25°C)	P <sub>T1</sub>	143	W
Total Power Dissipation (T <sub>A</sub> = 25°C)	P <sub>T2</sub>	1.8	W
Channel Temperature	T <sub>ch</sub>	175	°C
Storage Temperature	T <sub>stg</sub>	-55 to +175	°C
Repetitive Avalanche Current <sup>Note2</sup>	I <sub>AR</sub>	37	A
Repetitive Avalanche Energy <sup>Note2</sup>	E <sub>AR</sub>	137	mJ

**Notes 1.** PW ≤ 10 μs, Duty Cycle ≤ 1%

**2.** T<sub>ch</sub> ≤ 150°C, R<sub>G</sub> = 25 Ω

### THERMAL RESISTANCE

Channel to Case Thermal Resistance	R <sub>th(ch-C)</sub>	1.05	°C/W
Channel to Ambient Thermal Resistance	R <sub>th(ch-A)</sub>	83.3	°C/W

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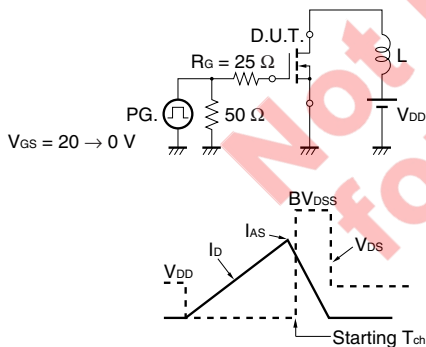
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**ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

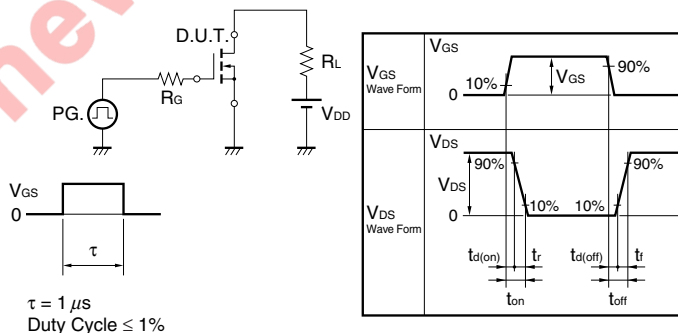
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 60\text{ V}, V_{GS} = 0\text{ V}$			1	$\mu\text{A}$
Gate Leakage Current	$I_{GSS}$	$V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$			$\pm 10$	$\mu\text{A}$
Gate to Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\ \mu\text{A}$	1.5		2.5	V
Forward Transfer Admittance <sup>Note</sup>	$ y_{fs} $	$V_{DS} = 5\text{ V}, I_D = 41\text{ A}$	19	68		S
Drain to Source On-state Resistance <sup>Note</sup>	$R_{DS(on)1}$	$V_{GS} = 10\text{ V}, I_D = 41\text{ A}$		5.9	7.4	$\text{m}\Omega$
	$R_{DS(on)2}$	$V_{GS} = 5\text{ V}, I_D = 41\text{ A}$		6.7	9.7	$\text{m}\Omega$
Input Capacitance	$C_{iss}$	$V_{DS} = 25\text{ V},$ $V_{GS} = 0\text{ V},$ $f = 1\text{ MHz}$		5700	8550	pF
Output Capacitance	$C_{oss}$			420	630	pF
Reverse Transfer Capacitance	$C_{rss}$			275	500	pF
Turn-on Delay Time	$t_{d(on)}$	$V_{DD} = 20\text{ V}, I_D = 41\text{ A},$ $V_{GS} = 10\text{ V},$ $R_G = 0\ \Omega$		28	70	ns
Rise Time	$t_r$			22	60	ns
Turn-off Delay Time	$t_{d(off)}$			79	160	ns
Fall Time	$t_f$			9	30	ns
Total Gate Charge	$Q_G$	$V_{DD} = 48\text{ V},$ $V_{GS} = 10\text{ V},$ $I_D = 82\text{ A}$		106	160	nC
Gate to Source Charge	$Q_{GS}$			29		nC
Gate to Drain Charge	$Q_{GD}$			35		nC
Body Diode Forward Voltage <sup>Note</sup>	$V_{F(S-D)}$	$I_F = 82\text{ A}, V_{GS} = 0\text{ V}$		0.9	1.5	V
Reverse Recovery Time	$t_{rr}$	$I_F = 82\text{ A}, V_{GS} = 0\text{ V},$ $di/dt = 100\text{ A}/\mu\text{s}$		43		ns
Reverse Recovery Charge	$Q_{rr}$			65		nC

**Note** Pulsed test

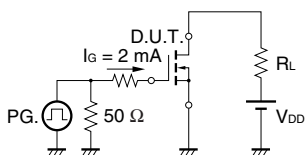
**TEST CIRCUIT 1 AVALANCHE CAPABILITY**



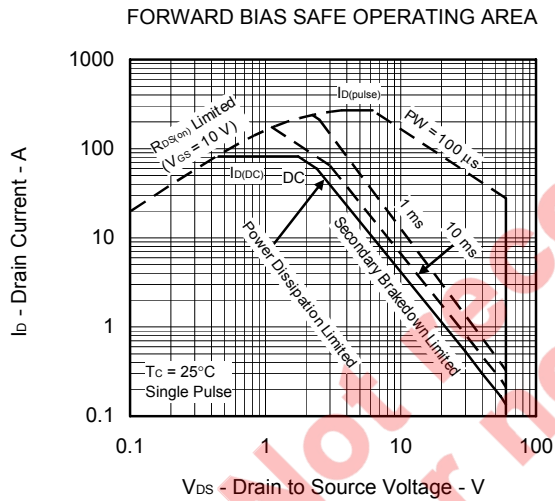
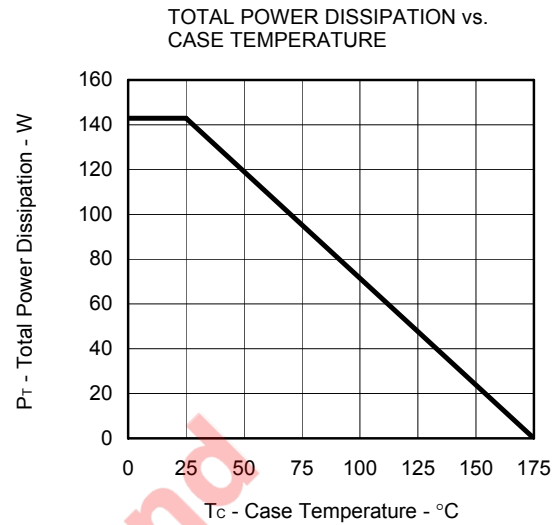
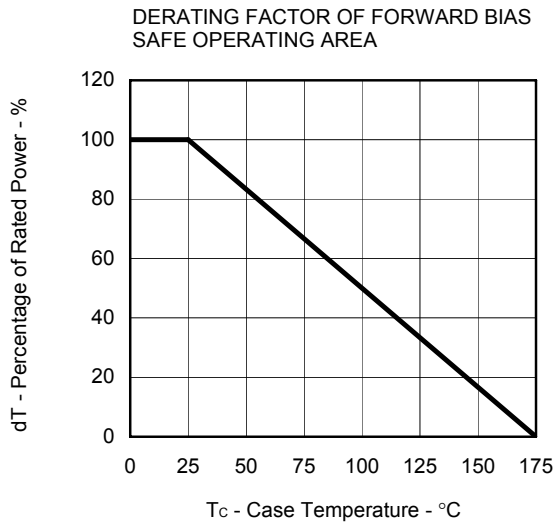
**TEST CIRCUIT 2 SWITCHING TIME**



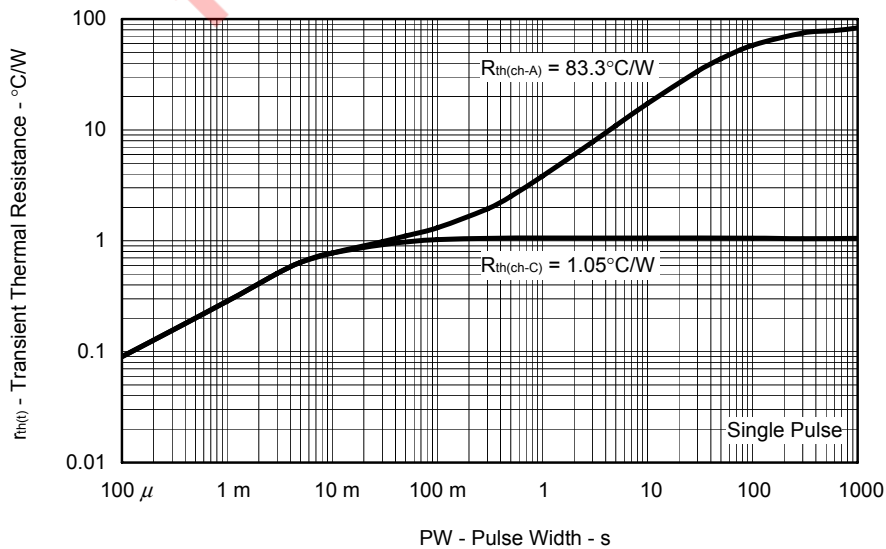
**TEST CIRCUIT 3 GATE CHARGE**



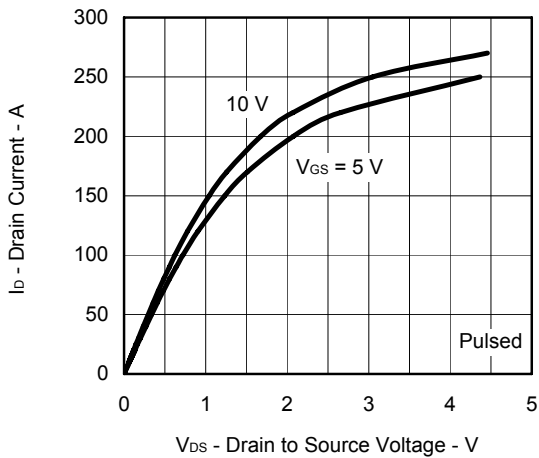
TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)



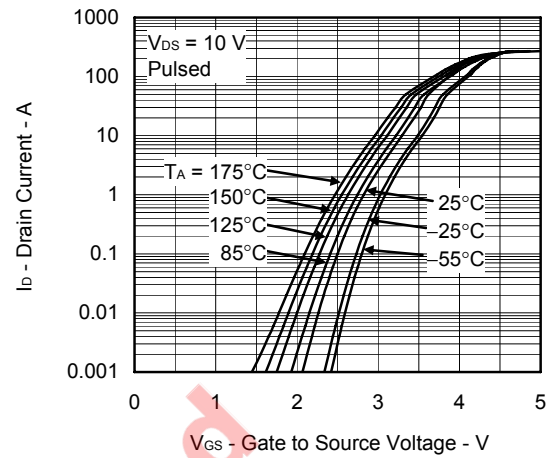
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



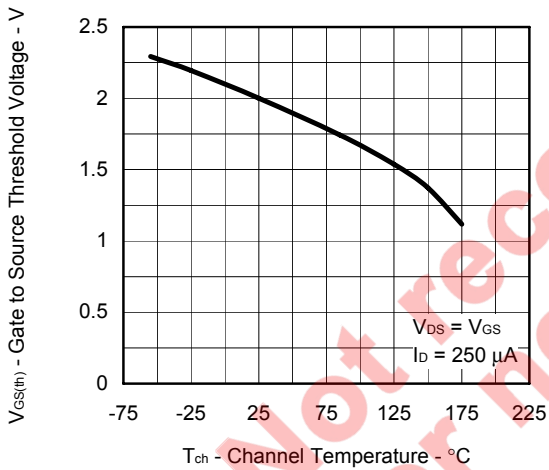
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



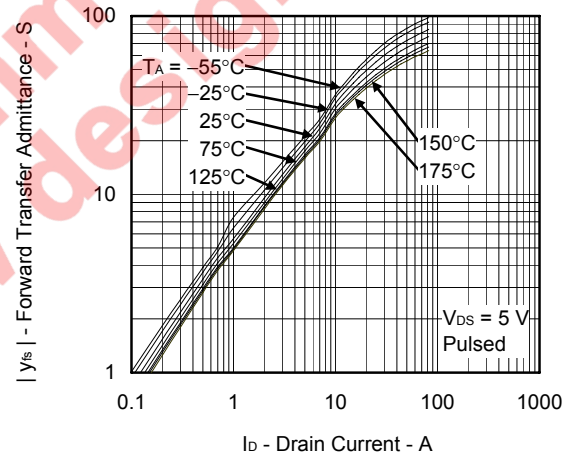
FORWARD TRANSFER CHARACTERISTICS



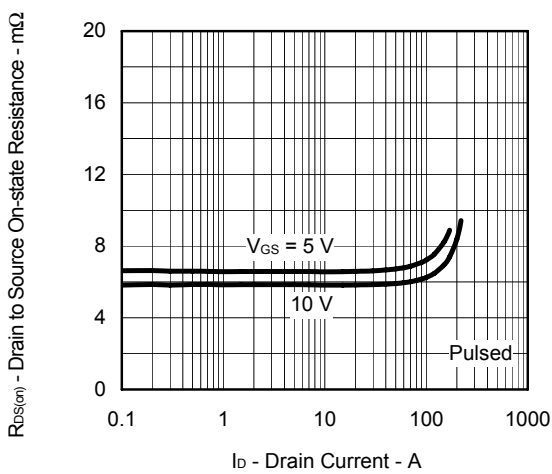
GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE



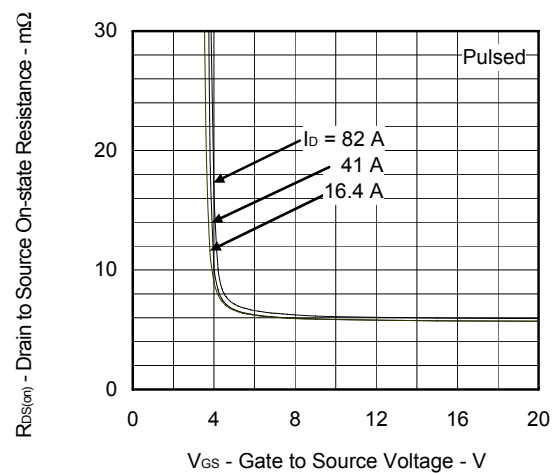
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



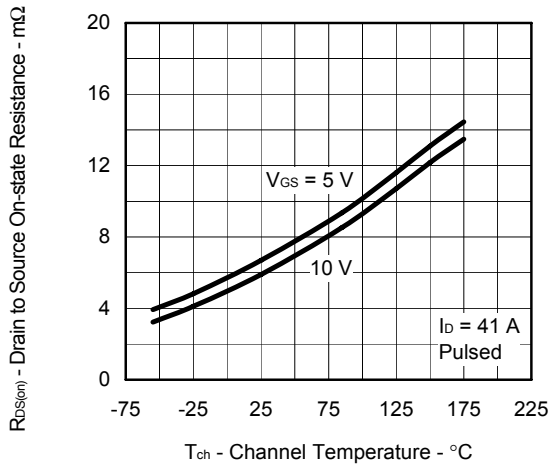
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



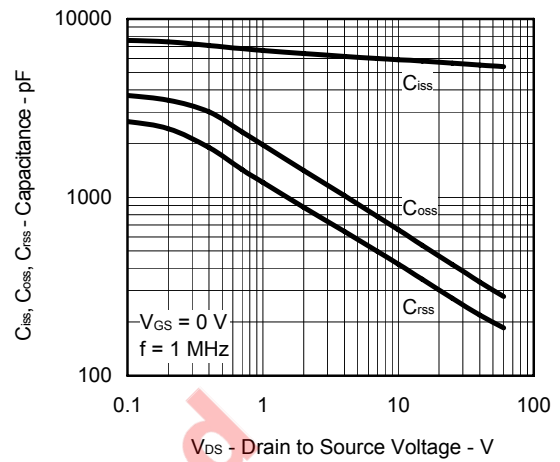
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



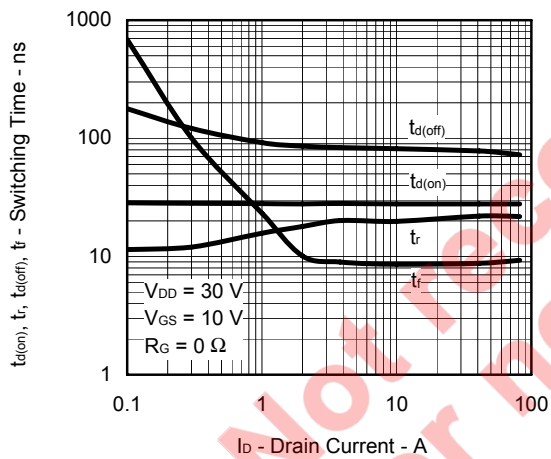
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



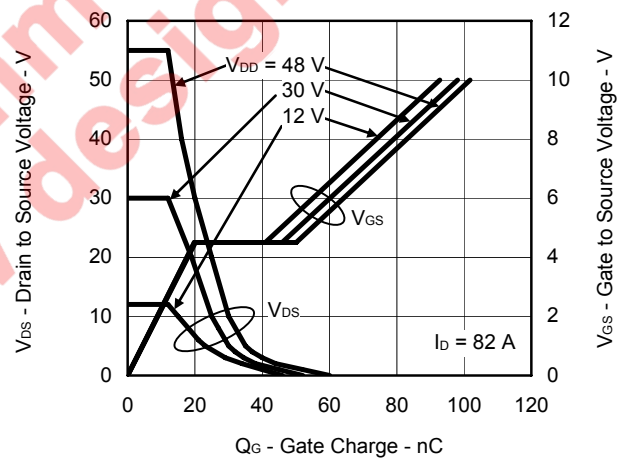
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



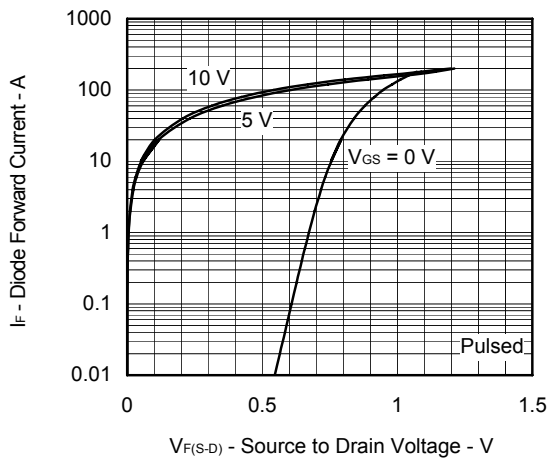
SWITCHING CHARACTERISTICS



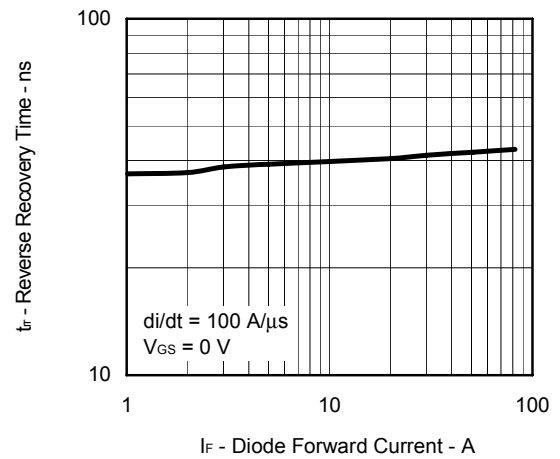
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE

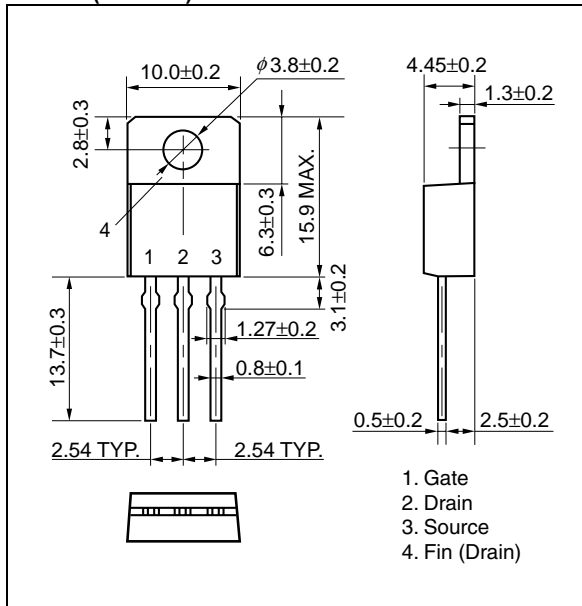


REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT

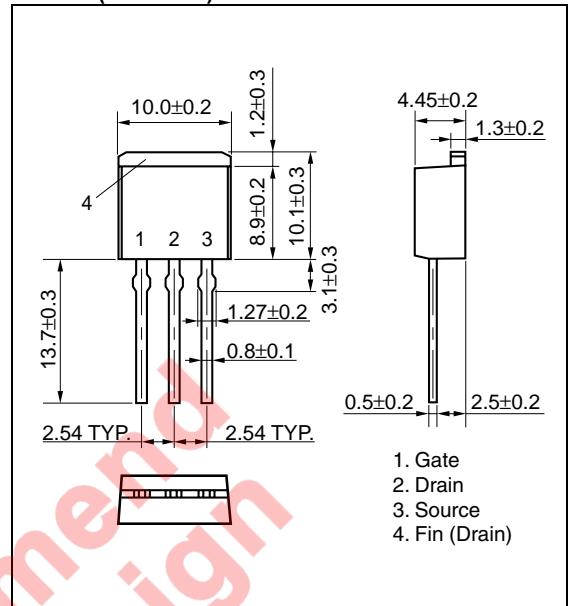


PACKAGE DRAWINGS (Unit: mm)

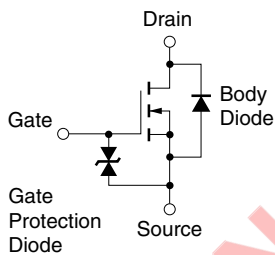
TO-220 (MP-25K)



TO-262 (MP-25SK)



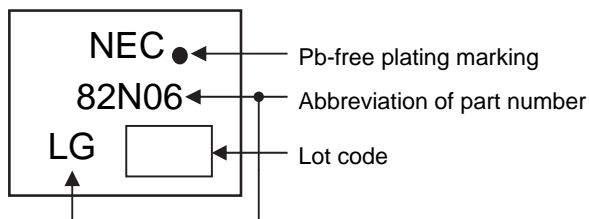
EQUIVALENT CIRCUIT



**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.



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**RECOMMENDED SOLDERING CONDITIONS**

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Semiconductor Device Mount Manual (<http://www.necel.com/pkg/en/mount/index.html>)

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Wave soldering NP82N06MLG, NP82N06NLG	Maximum temperature (Solder temperature): 260°C or below Time: 10 seconds or less Maximum chlorine content of rosin flux: 0.2% (wt.) or less	THDWS
Partial heating NP82N06MLG, NP82N06NLG	Maximum temperature (Pin temperature): 350°C or below Time (per side of the device): 3 seconds or less Maximum chlorine content of rosin flux: 0.2% (wt.) or less	P350

**Caution** Do not use different soldering methods together (except for partial heating).

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